

# **Excellent Integrated System Limited**

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Diodes Incorporated 74LVC126AT14-13

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#### **QUADRUPLE 3-STATE BUFFERS**

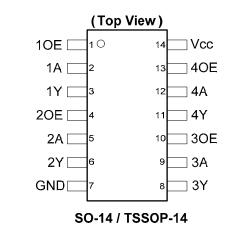
#### Description

The 74LVC126A provides four independent buffers with three state outputs. Each output is independently controlled by an associated output enable pin (OE) which places the device in the high impedance state when driven low. The device is designed for operation with a power supply range of 1.65V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using IOFF. The IOFF circuitry disables the output preventing damaging current backflow when the device is powered down.

#### Features

- Supply Voltage Range from 1.65V to 5.5V
- Sinks 24mA at V<sub>CC</sub> = 3.3V
- CMOS low power consumption
- IOFF Supports Partial-Power-Down Mode Operation
- Inputs or outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5.5V allowing for voltage translation applications.
- ESD Protection Exceeds JESD 22
  - 200-V Machine Model (A115-A)
  - 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

# Pin Assignments



#### Applications

- Voltage Level Shifting
- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
  - PCs, networking, notebooks, ultrabooks, netbooks
  - Computer peripherals, hard drives, CD/DVD ROM
  - TV, DVD, DVR, set top box
- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  - See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
    Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</li>

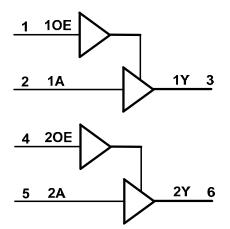


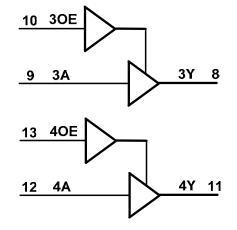


### **Pin Descriptions**

Pin Number	Pin Name	Description
1	10E	Data Enable Input (active high)
2	1A	Data Input
3	1Y	Data Output
4	20E	Data Enable Input (active high)
5	2A	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	ЗA	Data Input
10	30E	Data Enable Input (active high)
11	4Y	Data Output
12	4A	Data Input
13	40E	Data Enable Input (active high)
14	V <sub>CC</sub>	Supply Voltage

#### Logic Diagram





### **Function Table**

Inp	Output	
OE	Α	Y
Н	н	н
Н	L	L
L	Х	Z





#### Symbol Description Rating Unit ESD HBM 2 ΚV Human Body Model ESD Protection ESD CDM 1 ΚV Charged Device Model ESD Protection ESD MM V Machine Model ESD Protection 200 -0.5 to +6.5 V Vcc Supply Voltage Range VI Input Voltage Range -0.5 to +6.5 V Vo Voltage applied to output in high impedance or IOFF state V -0.5 to +6.5 Voltage applied to output in high or low state Vo -0.3 to V<sub>CC</sub> +0.5 V $I_{IK}$ Input Clamp Current $V_{I} < 0$ -50 mΑ Ιок Output Clamp Current -50 mΑ V<sub>O</sub> <0 lo Continuous output current ±50 mΑ $I_{CC}$ , $I_{GND}$ Continuous current through V<sub>CC</sub> or GND ±100 mΑ ТJ **Operating Junction Temperature** -40 to +150 °C °C T<sub>STG</sub> Storage Temperature -65 to +150 **Total Power Dissipation** 500 mW PTOT

#### Absolute Maximum Ratings (Note 4) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

#### Recommended Operating Conditions (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit	
Vcc	Supply Voltage		1.65	5.50	V	
VI	Input Voltage		0	5.5	V	
N/		Active Mode	0	Vcc	V	
Vo	Output Voltage	V <sub>CC</sub> = 0V; Power Down Mode	0	5.5	V	
	La contra contra contra contra la contra de la	V <sub>CC</sub> = 1.65V to 2.7V		20		
$\Delta t/\Delta V$ Input transition rise or fall rate		V <sub>CC</sub> = 2.7V to 3.6V		10	ns/V	
TA	Operating free-air temperature		-40	+125	°C	

Note: 5. Unused inputs should be held at  $V_{CC}$  or Ground.





#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

0	Barrantan	Test		T <sub>A</sub> = -40°C	C to +85°C	T <sub>A</sub> = -40°C	to +125°C	11
Symbol	Parameter	Test Conditions	V <sub>cc</sub>	Min	Max	Min	Max	Unit
			1.65V to 1.95V	0.65 X V <sub>CC</sub>		0.65 X V <sub>CC</sub>		
VIH	High-level Input Voltage		2.3V to 2.7V	1.7		1.6		V
	vollage		2.7V to 3.6V	2.0		2.0		
			1.65V to 1.95V		0.35 X V <sub>CC</sub>		0.35 X V <sub>CC</sub>	
VIL	Low-level input voltage		2.3V to 2.7V		0.7		0.7	V
	vollage		2.7V to 3.6V		0.8		0.8	
		I <sub>OH</sub> = -100µА	1.65V to 3.6V	V <sub>CC</sub> – 0.2		V <sub>CC</sub> - 0.3		
		I <sub>OH</sub> = -4mA	1.65V	1.2				
	High Level	I <sub>OH</sub> = -8mA	2.3V	1.9				
V <sub>OH</sub>	Output Voltage		2.7V	2.2		2.05		V
		I <sub>OH</sub> = -12mA	3.0V	2.3		2.1		
		I <sub>OH</sub> = -24mA	3.0V	2.2		2.0		
		I <sub>OH</sub> = 100µА	1.65V to 3.6V		0.2		0.3	
		I <sub>OH</sub> = 4mA	1.65V		0.45		0.6	
	High-level Output	I <sub>OH</sub> = 8mA	2.3V		0.70		0.85	
V <sub>OL</sub>	Voltage	10.1	2.7V		0.40		0.6	V
		I <sub>OH</sub> = 12mA	3.0V		0.55		0.6	
		I <sub>OH</sub> =-24mA	3.0V		0.55		0.6	
I <sub>I</sub>	Input Current	V <sub>I</sub> =GND to 5.5V	3.6V		± 5		± 20	μA
I <sub>OZ</sub>	Z State Leakage Current	$V_0 = GND \text{ or } 5.5V$	3.6V		± 10		± 20	μA
I <sub>OFF</sub>	Power Down Leakage Current	$V_{\rm I}$ or $V_{\rm O}$ = 0V to 3.6V	0		10		20	μA
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O=0$	3.6V		10		40	μA
Δlcc	Additional Supply Current	One input at V <sub>CC</sub> –0.6V Other	2.7V to 3.6V		500		5000	μA





# Switching Characteristics

_	From	То	Test Conditions		T <sub>A</sub> = +25°	°C	-40°C t	o +85°C	-40°C to	o +125℃	
Parameter	(Input)	(Output)	See Figure 1	Min	Тур	Max	Min	Max	Min	Max	Unit
			Vcc = 1.8V ± 0.15V	1.0	4.2	9.3	1.0	9.8	1.0	11.3	
t <sub>pd</sub>	А	Y	Vcc = 2.5V ± 0.2V	1.0	2.7	6.7	1.0	7.2	1.0	9.3	ns
P -			Vcc = 2.7V	1.0	2.9	5.0	1.0	5.2	1.0	6.5	
			Vcc = 3.3V ± 0.3V	1.0	2.5	4.5	1.0	4.7	1.0	6.0	6.0
			Vcc = 1.8V ± 0.15V	1.0	4.8	9.5	1.0	10	1.0	11.5	
t <sub>en</sub>	OE	Y	Vcc = 2.5V ± 0.2V	1.0	2.1	7.8	1.0	8.3	1.0	10.4	ns
			Vcc = 2.7V	1.0	2.3	6.1	1.0	6.3	1.0	8.0	
			Vcc = 3.3V ± 0.3V	1.0	2.5	5.5	1.0	5.7	1.0	7.5	
			Vcc = 1.8 V ± 0.15V	1.0	4.4	12.1	1.0	12.5	1.0	14.1	
t <sub>dis</sub>	OE	Y	Vcc = 2.5V ± 0.2V	1.0	2.7	8.2	1.0	8.7	1.0	10.8	ns
			Vcc = 2.7V	1.0	2.7	6.5	1.0	6.7	1.0	8.5	
			Vcc = 3.3V ± 0.3V	1.0	2.3	5.8	1.0	6.0	1.0	7.5	
t <sub>SK(0)</sub>			Vcc = 3.3V ± 0.3V			1.0		1.0		1.5	ns

#### **Operating Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	V <sub>cc</sub> = 1.8V Typ	V <sub>CC</sub> = 2.5V Typ	V <sub>cc</sub> = 3.3V Typ	Unit
$C_{\text{pd}}$	Power dissipation capacitance per gate	f = 10 MHz	7.3	11.2	14.9	pF
Cı	Input Capacitance	$V_i = V_{CC} - or$ GND	4	4	4	pF

### Package Characteristics

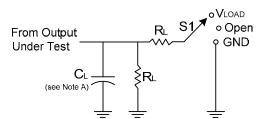
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit	
0	Thermal Resistance	SO-14	(Nata C)		TBD		°C/W	
θ <sub>JA</sub>	Junction-to-Ambient	TSSOP-14	(Note 6)		159		C/w	
0	Thermal Resistance	SO-14	(Note 6)		TBD		°C/W	
$\theta_{\rm JC}$	Junction-to-Case	TSSOP-14	(Note 6)		25		C/VV	

Note: 6. Test condition for SO-14 and TSSOP-14: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.





#### **Parameter Measuement Information**

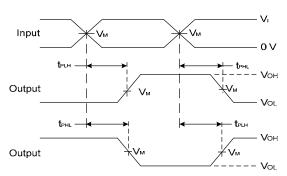


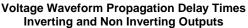
TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	VLOAD
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

V <sub>cc</sub>	Inp	outs	V <sub>M</sub>	VLOAD	C	R∟	V۵
VCC	VI	t <sub>r</sub> /t <sub>f</sub>	¥М	V LOAD	υL	κL	
1.8V±0.15V	Vcc	≤2ns	V <sub>CC</sub> /2	2 x V <sub>CC</sub>	30pF	1ΚΩ	0.15V
2.5V±0.2V	V <sub>CC</sub>	≤2ns	V <sub>CC</sub> /2	2 x V <sub>CC</sub>	30pF	500Ω	0.15V
2.7V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V
3.3V±0.3V	2.7V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V



#### **Voltage Waveform Pulse Duration**

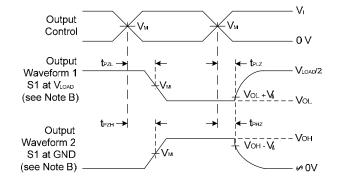




Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate  $\leq$  10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D.  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}$  are the same as  $t_{\text{dis.}}$
- E.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{EN0}$
- F. tPLH and tPHL are the same as tPD.

#### Figure 1. Load Circuit and Voltage Waveforms

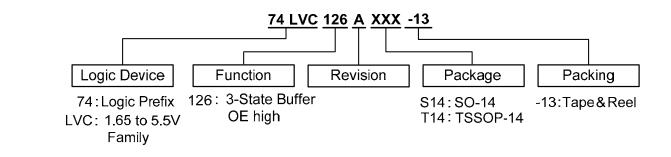


#### Voltage Waveform Enable and Disable Times Low and High Level Enabling





### **Ordering Information**

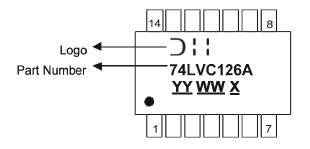


	Dovice	Package Packaging		13" Tape	and Reel
	Device	Code	(Note 5)	Quantity	Part Number Suffix
Pb,	74LVC126AS14-13	S14	SO-14	2500/Tape & Reel	-13
Pb,	74LVC126AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13

Notes: 7. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

#### **Marking Information**

#### (1) SO-14, TSSOP-14



 $\underline{YY} : Year : 08, 09, 10 \sim$  $\underline{WW} : Week : 01 \sim 52; 52$ represents 52 and 53 week  $\underline{X} : Internal Code$ 

Part Number	Package
74LVC126AS14	SO-14
74LVC126AT14	TSSOP-14



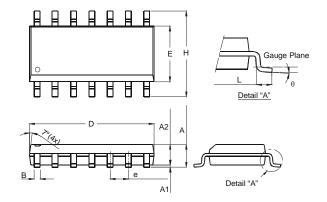
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#### 74LVC126A

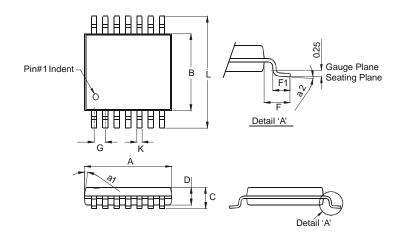
#### Package Outline Dimensions (All dimensions in mm.)

#### Package Type: SO-14



	SO-14						
Dim	Min	Max					
Α	1.47	1.73					
A1	0.10	0.25					
A2	1.45	Тур					
В	0.33	0.51					
D	8.53	8.74					
Е	3.80	3.99					
е	1.27	Тур					
Н	5.80	6.20					
L	0.38	1.27					
θ	0°	8°					
All Di	mensions	s in mm					

#### Package Type: TSSOP-14



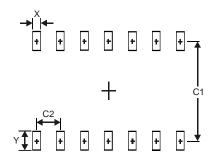
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С		1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
Κ	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		





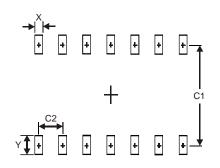
# **Suggested Pad Layout**

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65





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